

PMN30XP 20 V, P-channel Trench MOSFET 23 February 2016

**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Enhanced power dissipation capability of 1400 mW

### 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Qu	ick reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage	-		-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	-6.8	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -5.2 A; T <sub>j</sub> = 25 °C		-	30	34	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	6 5 4	D
2	D	drain		
3	G	gate		G
4	S	source	TSOP6 (SOT457)	\$ 017aaa257
5	D	drain	-	
6	D	drain		

# 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMN30XP	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

### 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN30XP	3A

### 8. Limiting values

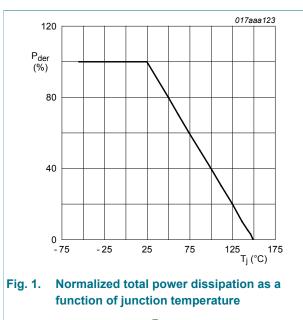
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

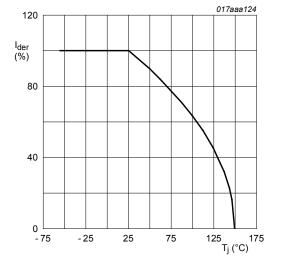
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-6.8	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-5.2	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-3.3	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-21	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	550	mW
			[1]	-	1.4	W
		T <sub>sp</sub> = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.3	А

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$



# Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_D(25^{\circ}C)} \times 100 \%$$

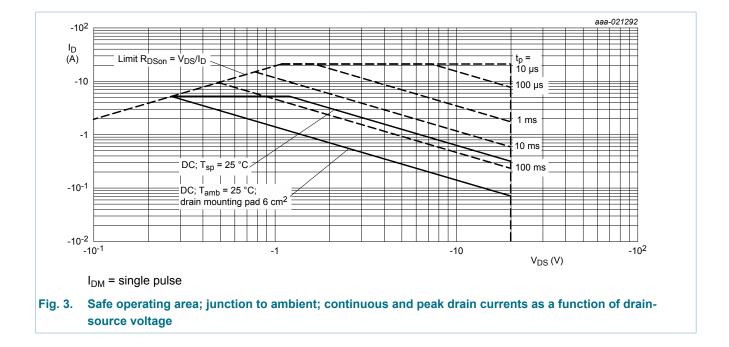
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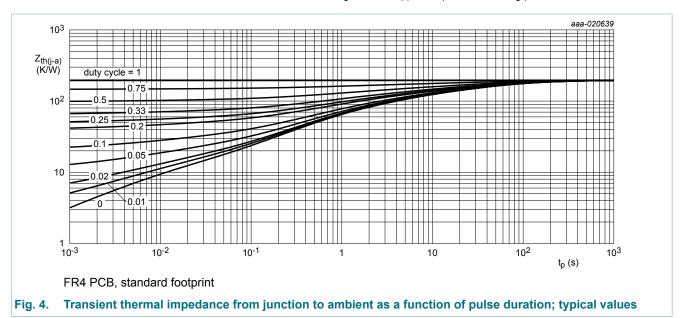
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### 9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	195	225	K/W
			[2]	-	78	90	K/W
		in free air; $t \le 5 s$	[2]	-	45	52	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	15	20	K/W

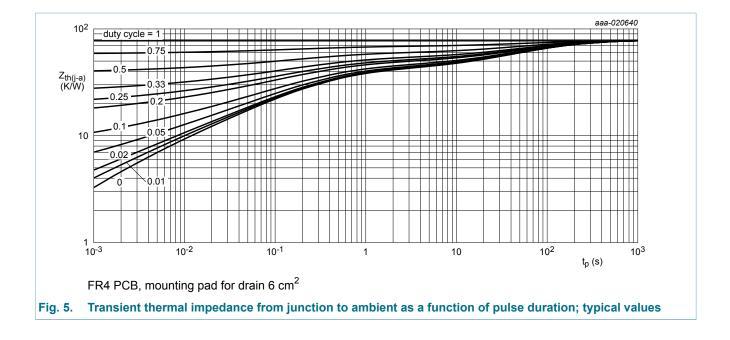
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



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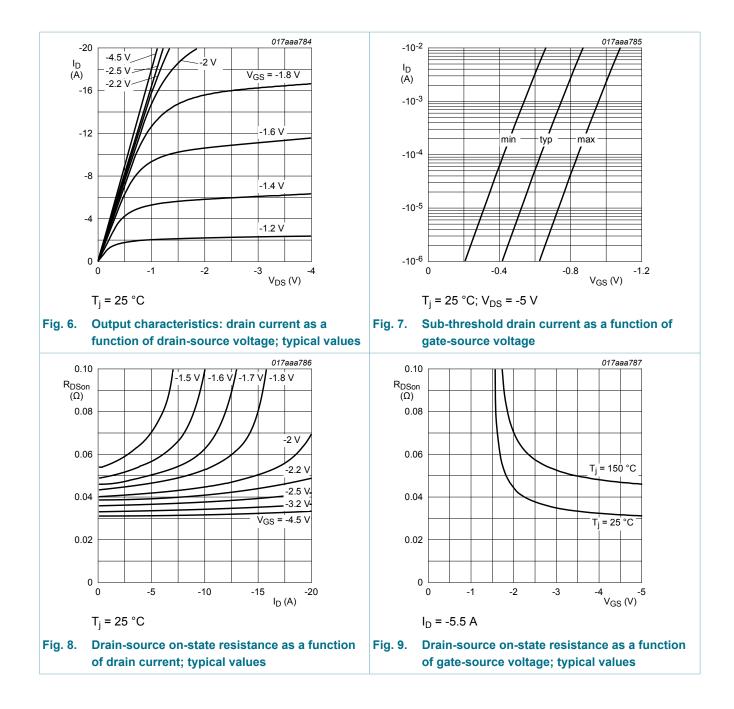
### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	1				
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.47	-0.68	-0.9	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		$V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -5.2 A; T <sub>j</sub> = 25 °C	-	30	34	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -5.2 A; T <sub>j</sub> = 150 °C	-	46	52	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -4.6 A; T <sub>j</sub> = 25 °C	-	35	44	mΩ
		V <sub>GS</sub> = -1.8 V; I <sub>D</sub> = -1 A; T <sub>j</sub> = 25 °C	-	45	65	mΩ
		V <sub>GS</sub> = -1.5 V; I <sub>D</sub> = -0.1 A; T <sub>j</sub> = 25 °C	-	65	130	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; I <sub>D</sub> = -5.3 A; T <sub>j</sub> = 25 °C	-	28	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	-	4.5	-	Ω
Dynamic ch	aracteristics	1				
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; I <sub>D</sub> = -5.5 A; V <sub>GS</sub> = -4.5 V;	-	15	23	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	2	-	nC
Q <sub>GD</sub>	gate-drain charge		-	4	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	1575	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	145	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	125	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -5.5 A; V <sub>GS</sub> = -4.5 V;	-	12	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C	-	42	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	62	-	ns
t <sub>f</sub>	fall time		-	23	-	ns
Source-drai	in diode	1	I		1	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.3 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

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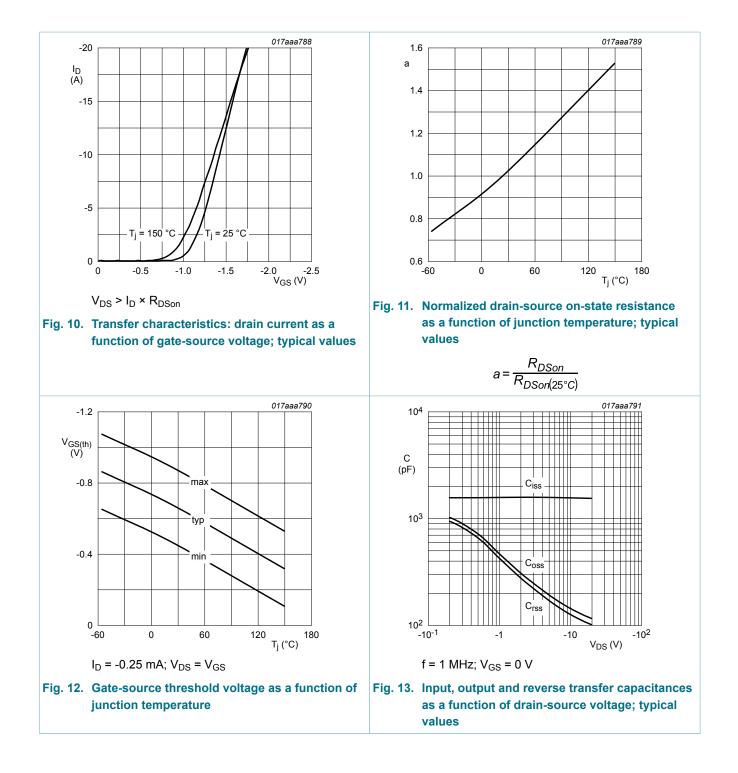
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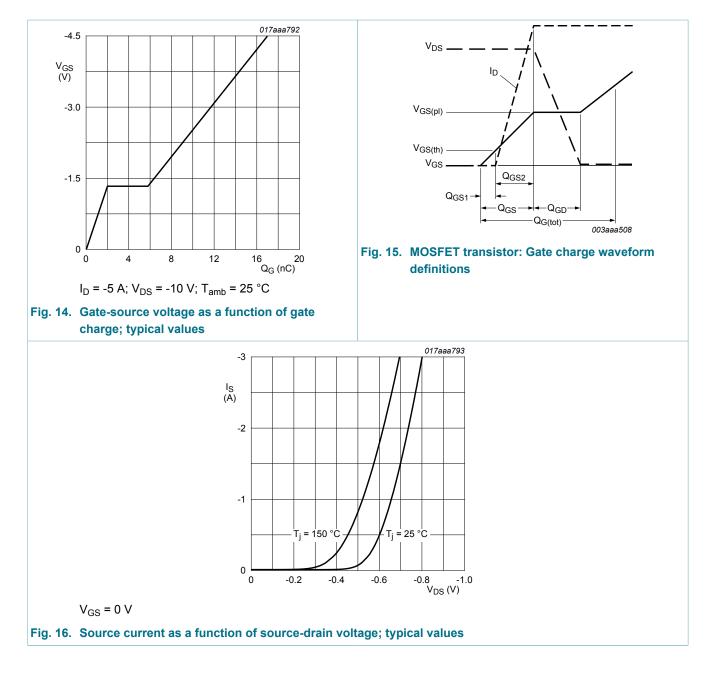
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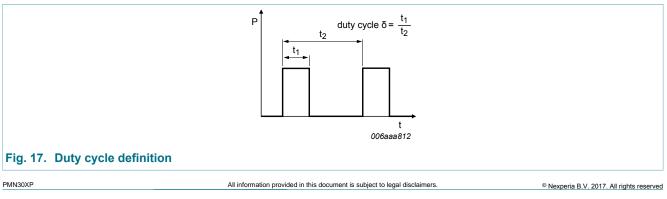


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# 11. Test information

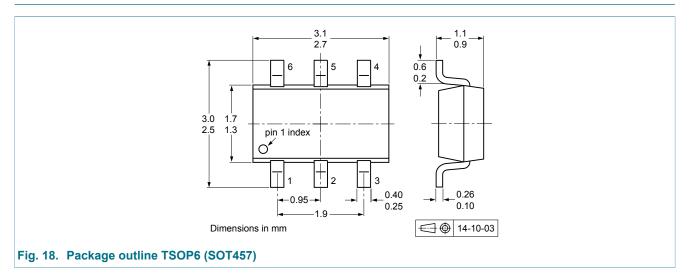


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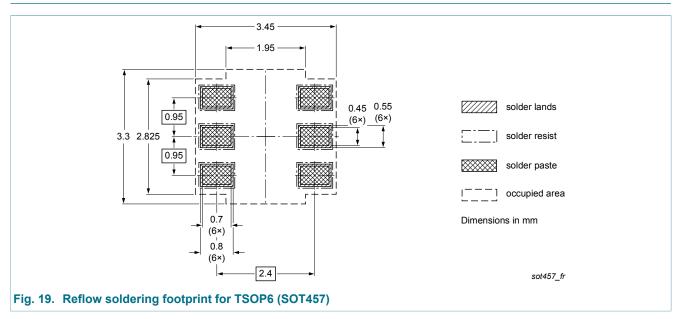
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### 12. Package outline

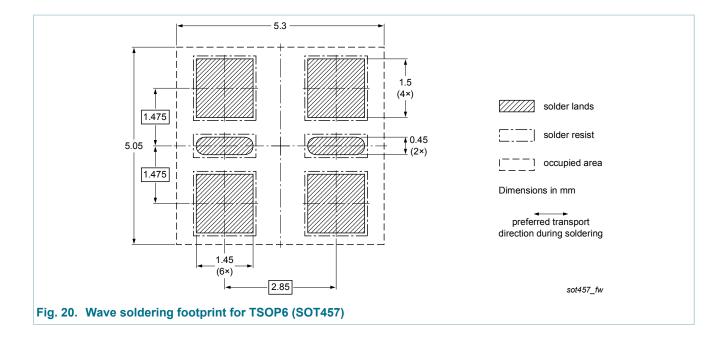


### 13. Soldering



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### 14. Revision history

Table 8. Revision his	le 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMN30XP v.1	20160223	Product data sheet	-	-			

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### 15. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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